## NSN 5962-01-234-3569

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View Online at https://aerobasegroup.com/nsn/5962-01-234-3569

Body Length:
1.485 inches
Body Width:
Between 0.590 inches and 0.625 inches
Body Height:
0.217 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Alq176 mlv
Features Provided:
Hermetically sealed and burn in and w/enable and ultraviolet erasable and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
17 input
Current Rating Per Characteristic:
50.00 milliamperes total supply
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.5 volts power source
Time Rating Per Chacteristic:
200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Prom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:

N/a

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Demilitarization:

No

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